

Surface Mount Attenuator 10 Watts, 3dB

The XRA10AA3SES is a high performance Alumina (Al2O3) chip attenuator intended as a cost competitive alternative to Beryllium Oxide (BeO). It is designed particularly for LTE and 5G wireless communication frequency bands. The high power handling makes the part ideal for inter-stage matching, directional couplers, and for use in isolators. The attenuator is also RoHS compliant!

General Specifications

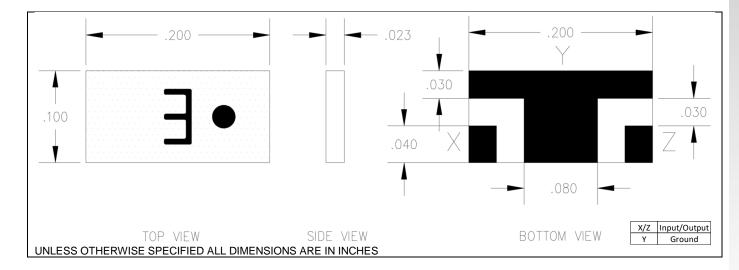
Resistive Element	Thick film
Substrate	Al2O3 Ceramic
Terminal Finish	Matte Tin over Nickel Barrier
Operating Temperature	-55 to +150°C (see de rating chart)
Tolerance is ± 0.010 ", unless otherwise specified. Designed to meet or exceed	

applicable portions of MIL-E-5400. All dimensions in inches.

Electrical Specifications

Attenuation Value:	3.0 ± 0.3 dB
Power:	10 Watts
Frequency Range:	DC – 6.0GHz
Input Return Loss:	20dB

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. Specifications subject to change.





Features:

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RoHS Compliant

10 Watts

Low Cost

Element

Low VSWR

100% Tested

DC - 6.0GHz

Al2O3 Ceramic

Non-Nichrome Resistive

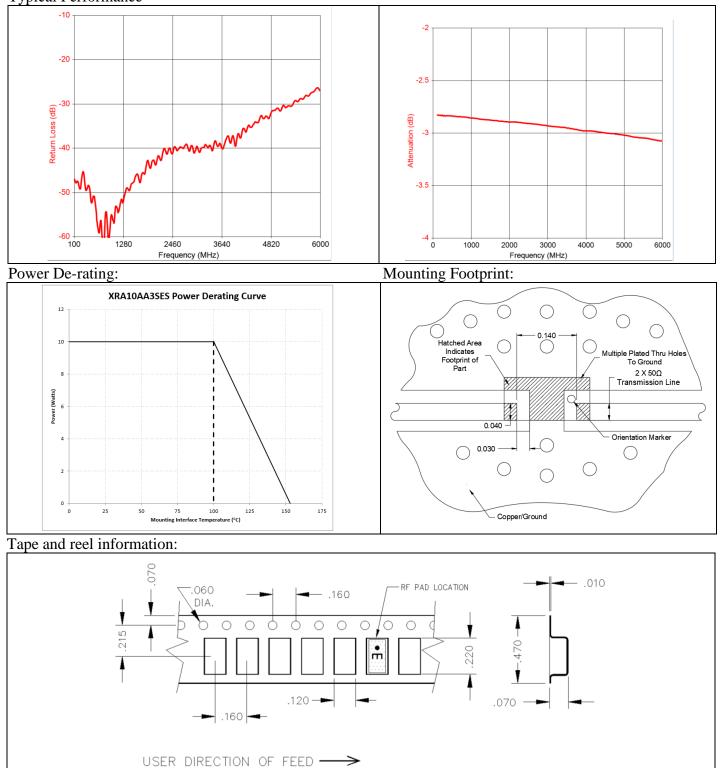


USA/Canada: Toll Free: Europe:

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XRA10AA3SES

Typical Performance



TAPE DETAIL & RF PAD ORIENTATION

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